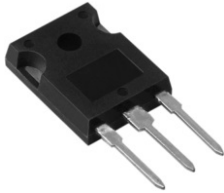
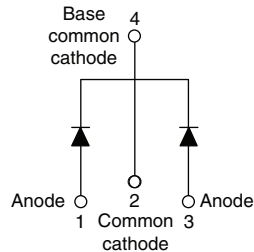


High Performance Schottky Generation 5.0, 2 x 20 A


TO-247AC

FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_F trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Fully lead (Pb)-free and RoHS compliant devices
- Designed and qualified for industrial level


**RoHS
COMPLIANT**
APPLICATIONS

- High efficiency SMPS
- Automotive
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- Dc-to-dc systems
- Increased power density systems

PRODUCT SUMMARY

$I_{F(AV)}$	2 x 20 A
V_R	100 V
Maximum V_F at 20 A at 125 °C	0.67 V

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		100	V
V_F	20 Apk, $T_J = 125$ °C (typical, per leg)	0.63	
T_J	Range	- 55 to 175	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MBR40H100WT-F	UNITS
Maximum DC reverse voltage	V_R	$T_J = 25$ °C	100	V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current <small>per leg</small> <small>per device</small>	$I_{F(AV)}$	50 % duty cycle at $T_C = 144$ °C, rectangular waveform	20	A
			40	
Maximum peak one cycle non-repetitive surge current	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	600	
		10 ms sine or 6 ms rect. pulse	200	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25$ °C, $I_{AS} = 1.5$ A, $L = 60$ mH	67.5	mJ
Repetitive avalanche current	I_{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse See fig. 8	I_{AS} at T_J max.	A

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^\circ\text{C}$	0.72	0.8	V
		40 A		0.85	0.9	
		20 A	$T_J = 125\text{ }^\circ\text{C}$	0.63	0.67	
		40 A		0.74	0.77	
Reverse leakage current per leg	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	1.2	50	μA
		$T_J = 125\text{ }^\circ\text{C}$		2.5	6	mA
Junction capacitance per leg	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		850	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body		8	-	nH
Maximum voltage rate of change	dV/dt	Rated V_R		-	10 000	V/ μs

Note

(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation	2	$^\circ\text{C/W}$
Maximum thermal resistance, junction to case per device			1	
Typical thermal resistance, case to heatsink	R_{thCS}		0.24	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AC	MBR40H100WT	

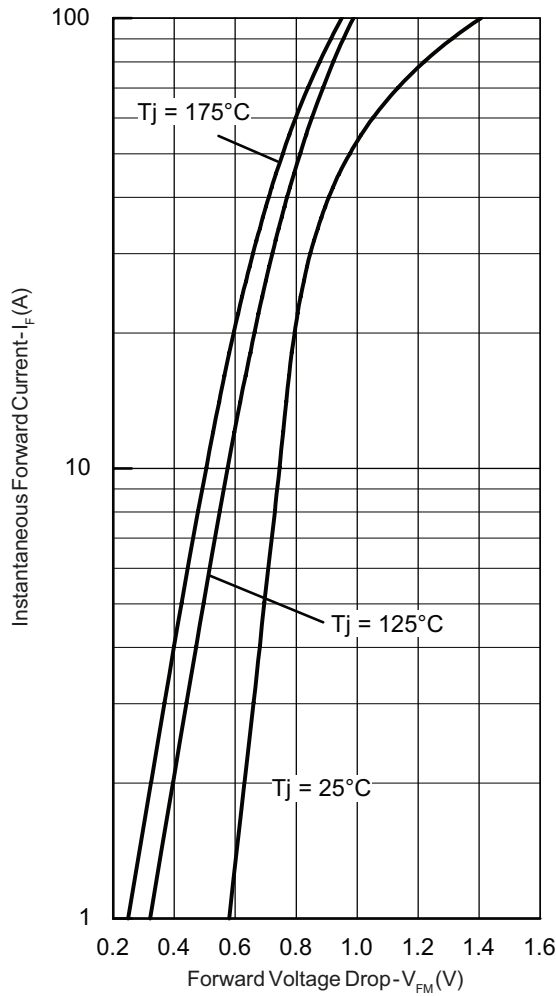


Fig. 1 - Maximum Forward Voltage Drop Characteristics

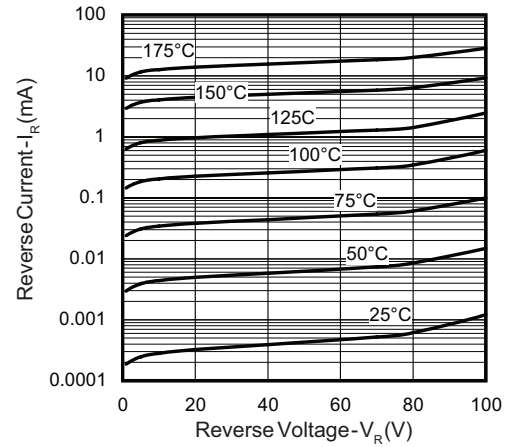


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

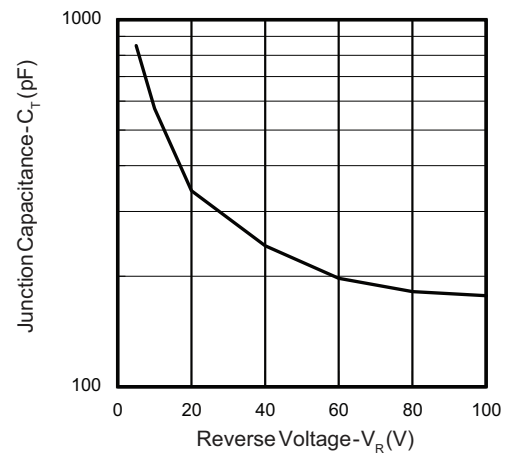


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

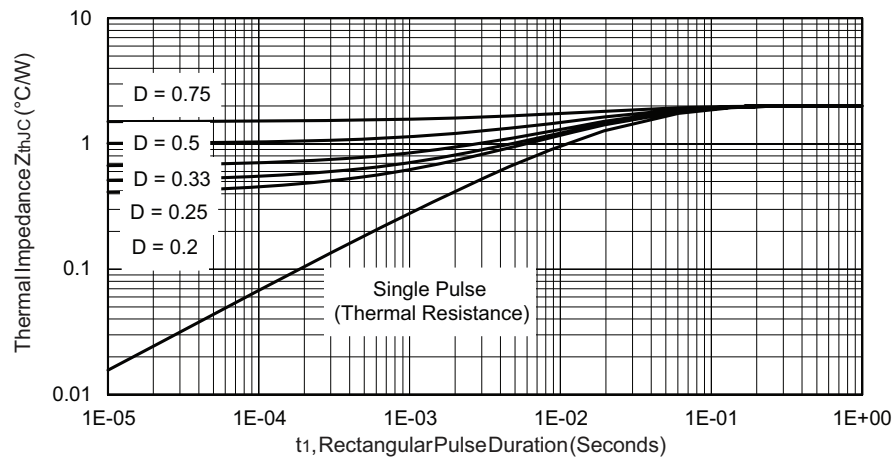


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

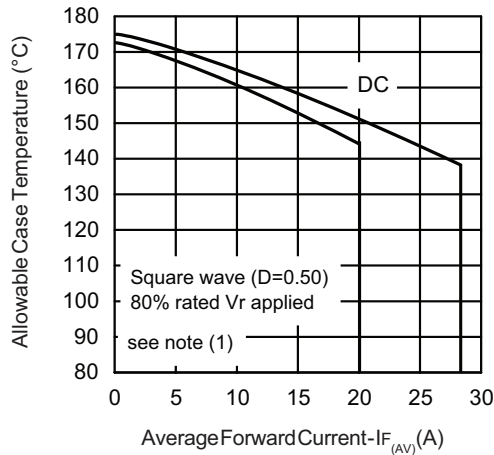


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

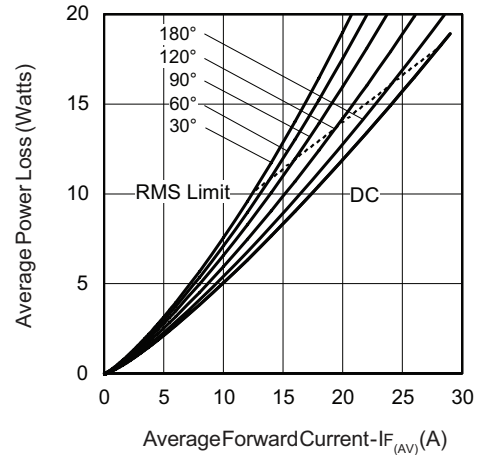


Fig. 6 - Forward Power Loss Characteristics

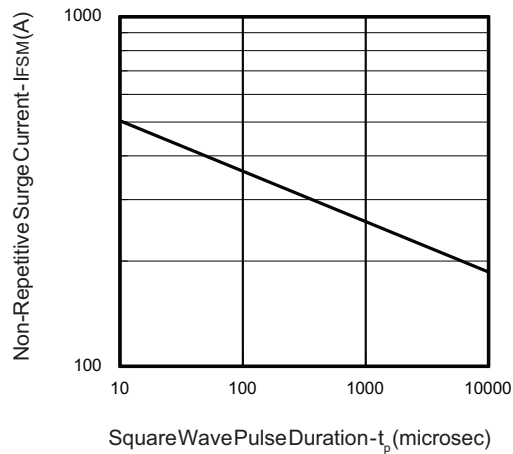


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

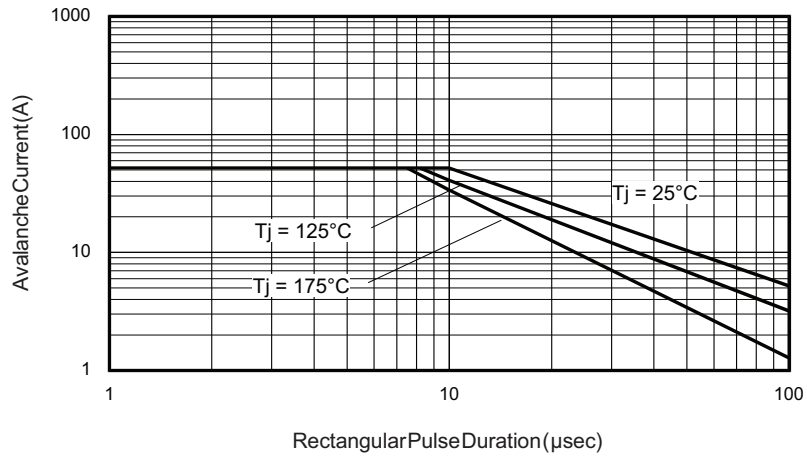


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

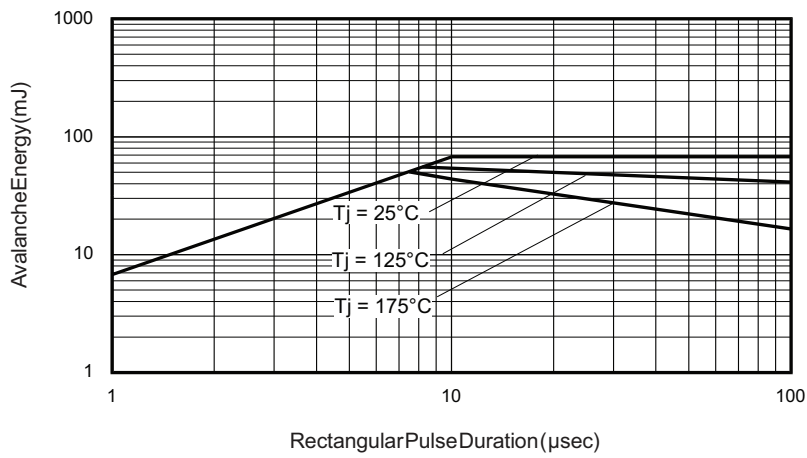


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

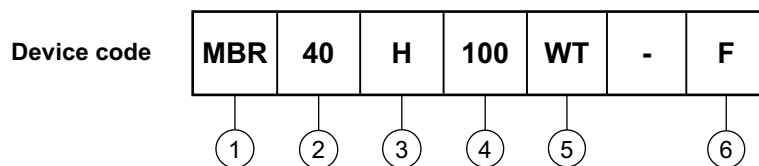
MBR40H100WT-F

Vishay High Power Products

High Performance
Schottky Generation 5.0, 2 x 20 A



ORDERING INFORMATION TABLE



- 1** - Schottky MBR series
- 2** - Current rating (40 = 40 A)
- 3** - H = High temperature
- 4** - Voltage code (100 V)
- 5** - WT = Circuit configuration: Center tap (dual) TO-247
- 6** - F = RoHS compliant and fully lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95223
Part marking information	http://www.vishay.com/doc?95007



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